



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



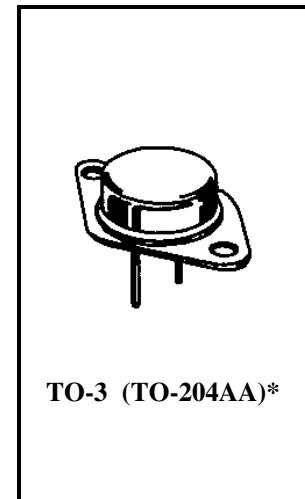
NPN HIGH POWER SILICON TRANSISTOR
Qualified per MIL-PRF-19500/ 371
Devices
2N3902
2N5157
Qualified Level
**JAN
JANTX**
MAXIMUM RATINGS

Ratings	Symbol	2N3902	2N5157	Unit
Collector-Emitter Voltage	V_{CEO}	400	500	Vdc
Emitter-Base Voltage	V_{EBO}	5.0	6.0	Vdc
Collector-Base Voltage	V_{CBO}	700		Vdc
Base Current	I_B	2.0		Adc
Collector Current	I_C	3.5		Adc
Total Power Dissipation	P_T	@ $T_A = +25^{\circ}C$ ⁽¹⁾	5.0	W
		@ $T_C = +75^{\circ}C$ ⁽²⁾	100	W
Operating & Storage Temperature Range	T_j, T_{stg}	-65 to +200		$^{\circ}C$

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max.	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.25	$^{\circ}C/W$

 1) Derate linearly 29 mW/ $^{\circ}C$ for $T_A > +25^{\circ}C$

 2) Derate linearly 0.8 W/ $^{\circ}C$ for $T_C > +75^{\circ}C$


*See Appendix A for Package Outline

ELECTRICAL CHARACTERISTICS

Characteristics	Symbol	Min.	Max.	Unit
-----------------	--------	------	------	------

OFF CHARACTERISTICS

Collector-Emitter Cutoff Current $V_{CE} = 325$ Vdc $V_{CE} = 400$ Vdc	2N3902 2N5157	I_{CEO}	250 250	μ Adc
Collector-Emitter Cutoff Current $V_{BE} = 1.5$ Vdc; $V_{CE} = 700$ Vdc		I_{CEX}	500	μ Adc
Emitter-Base Cutoff Current $V_{EB} = 5.0$ Vdc $V_{EB} = 6.0$ Vdc	2N3902 2N5157	I_{EBO}	200 200	μ Adc

ON CHARACTERISTICS⁽³⁾

Base-Emitter Saturation Voltage $I_C = 1.0$ Adc; $I_B = 0.1$ Adc $I_C = 3.5$ Adc; $I_B = 0.7$ Adc		$V_{BE(sat)}$	1.5 2.0	Vdc
Collector-Emitter Saturation Voltage $I_C = 1.0$ Adc; $I_B = 0.1$ Adc $I_C = 3.5$ Adc; $I_B = 0.7$ Adc		$V_{CE(sat)}$	0.8 2.5	Vdc

2N3902, 2N5157 JAN SERIES

ELECTRICAL CHARACTERISTICS (con't)

Characteristics	Symbol	Min.	Max.	Unit
ON CHARACTERISTICS⁽³⁾ (con't)				
Forward-Current Transfer Ratio I _C = 0.5 Adc; V _{CE} = 5.0 Vdc I _C = 1.0 Adc; V _{CE} = 5.0 Vdc I _C = 2.5 Adc; V _{CE} = 5.0 Vdc I _C = 3.5 Adc; V _{CE} = 5.0 Vdc	h _{FE}	25 30 10 5	90	
Collector-Emitter Sustaining Voltage I _C = 100 mAdc	V _{CEO(sus)}	325 400		Vdc

DYNAMIC CHARACTERISTICS

Small-Signal Short-Circuit Forward Current Transfer Ratio I _C = 0.2 Adc; V _{CE} = 10 Vdc, f = 1 MHz	h _{fc}	2.5	25	
Output Capacitance V _{CB} = 10 Vdc; I _E = 0, 100 kHz ≤ f ≤ 1.0 MHz	C _{obo}		250	pF

SWITCHING CHARACTERISTICS

Turn-On Time V _{CC} = 125 Vdc; I _C = 1.0 Adc; I _{B1} = 0.1 Adc	t _{on}		0.8	μs
Turn-Off Time V _{CC} = 125 Vdc; I _C = 1.0 Adc; I _{B1} = 0.1 Adc; -I _{B2} = 0.50 Adc	t _{off}		1.7	μs

SAFE OPERATING AREA

DC Tests (continuous)				
T _C = +25°C; t ≥ 1.0 s (See Figure 3 of MIL-PRF-19500/371)				
Test 1				
V _{CE} = 28.6 Vdc, I _C = 3.5 Adc				
Test 2				
V _{CE} = 70 Vdc, I _C = 1.43 Adc				
Test 3				
V _{CE} = 325 Vdc, I _C = 55 mAdc	2N3902			
V _{CE} = 400 Vdc, I _C = 35 mAdc	2N5157			
Switching Tests				
Load condition C (unclamped inductive load)				
T _C = 25°C; duty cycle ≤ 10%; R _S = 0.1 Ω (See Figure 4 of MIL-PRF-19500/371)				
Test 1				
t _p = approximately 3 ms (vary to obtain I _C); R _{BB1} = 20 Ω; V _{BB1} = 10 Vdc; R _{BB2} = 3 kΩ; V _{BB2} = 1.5 Vdc; V _{CC} = 50 Vdc; I _C = 3.5 Adc; L = 60 mH; R = 3 Ω; R _L ≤ 14Ω.				
Test 2				
t _p = approximately 3 ms (vary to obtain I _C); R _{BB1} = 100 Ω; V _{BB1} = 10 Vdc; R _{BB2} = 3 kΩ; V _{BB2} = 1.5 Vdc; I _C = 0.6 Adc V _{CC} = 50 Vdc; L = 200 mH; R = 8 Ω; R _L ≤ 83Ω.				
Switching Tests				
Load condition (clamped inductive load)				
T _C = +25°C; duty cycle ≤ 10%. (See Figure 5 of MIL-PRF-19500/371)				
Test 1				
t _p = approximately 30 ms (vary to obtain I _C); R _S = 0.1 Ω; R _{BB1} = 20 Ω; V _{BB1} = 10 Vdc; R _{BB2} = 100 Ω; V _{BB2} = 1.5 Vdc; V _{CC} = 50 Vdc; I _C = 3.5 Adc; L = 60 mH; R = 3 Ω; R _L ≥ 0Ω. (A suitable clamping circuit or diode can be used.)				
Clamp Voltage = 400 +0, -5 Vdc	2N3902			
Clamp Voltage = 500 +0, -5 Vdc	2N5157			
(Clamped voltage must be reached)				

3.) Pulse Test: Pulse Width = 300μs, Duty Cycle ≤ 2.0%.